

Amendments to the Claims:

The following listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Currently Amended) An electroluminescent ~~device~~ device, comprising:
first electrodes;
electroluminescent layers disposed over the first electrodes;
a second electrode disposed to over the electroluminescent layers; and
a barrier layer in ~~direct~~ contact with the second electrode,
~~wherein~~ at least the surface of the second electrode facing the barrier layer
~~comprises including~~ an inorganic oxide, and
at least the surface of the barrier layer facing the second electrode ~~comprises~~
including an inorganic compound.
2. (Currently Amended) The electroluminescent device according to claim 1,
~~wherein~~ the second electrode ~~comprises including~~ indium tin oxide or indium zinc oxide.
3. (Currently Amended) The electroluminescent device according to claim 1,
~~wherein~~ the second electrode ~~covers~~ covering side faces and upper faces of the
electroluminescent layers.
4. (Currently Amended) The electroluminescent device according to claim 1,
~~wherein~~ the barrier layer ~~comprises including~~ at least one sublayer composed of a silicon
compound.
5. (Currently Amended) The electroluminescent device according to claim 4,
~~wherein~~ the barrier layer ~~comprises including~~ a sublayer in contact with the second electrode,
the sublayer being composed of silicon oxide.

6. (Currently Amended) The electroluminescent device according to claim 4, ~~wherein~~ the barrier layer ~~comprises~~ including a sublayer in contact with the second electrode, the sublayer being composed of silicon nitride.

7. (Currently Amended) The electroluminescent device according to claim 4, ~~wherein~~ the barrier layer ~~comprises~~ including a sublayer in contact with the second electrode, the sublayer being composed of silicon nitride oxide.

8. (Currently Amended) The electroluminescent device according to claim 1, further comprising:

an insulating layer disposed around the second electrode, the insulating layer being composed of a silicon compound,

~~wherein~~ the barrier layer ~~extends~~ extending to the insulating layer.

9. (Currently Amended) The electroluminescent device according to claim 1, further comprising:

a protective layer ~~for covering~~ that covers the barrier layer.

10. (Original) The electroluminescent device according to claim 9, further comprising:

an adhesive layer disposed between the barrier layer and the protective layer.

11. (Currently Amended) The electroluminescent device according to claim 10, ~~wherein~~ the adhesive layer ~~comprises~~ including a material that is softer than that of the protective layer.

12. (Currently Amended) An electronic apparatus comprising ~~an~~ the electroluminescent device according to claim 1.

13. (Currently Amended) A method for manufacturing an electroluminescent device, ~~comprising the steps of:~~ comprising:

forming a second electrode ~~to~~ over electroluminescent layers disposed over a first electrode, the second electrode having a surface being composed of an inorganic oxide; and

forming a barrier layer such that at least one portion of the barrier layer comes into ~~direct~~ contact with the second electrode, the barrier layer being composed of an inorganic compound.

14. (Currently Amended) The method for manufacturing an electroluminescent device according to claim 13, ~~wherein~~ the second electrode ~~is being~~ formed by vapor phase deposition.

15. (Currently Amended) The method for manufacturing an electroluminescent device according to claim 13, ~~wherein~~ the barrier layer ~~is being~~ formed by vapor phase deposition.

16. (Currently Amended) The method for manufacturing an electroluminescent device according to ~~any one of~~ claim 13, ~~wherein~~ the second electrode ~~comprises including~~ indium tin oxide or indium zinc oxide.

17. (Currently Amended) The method for manufacturing an electroluminescent device according to ~~any one of~~ claim 13, ~~wherein~~ the barrier layer ~~comprises including~~ a silicon compound.

18. (Currently Amended) The method for manufacturing an electroluminescent device according to claim 17, ~~wherein~~ the barrier layer ~~has having~~ a sublayer in contact with the second electrode, the sublayer being composed of silicon oxide.

19. (Currently Amended) The method for manufacturing an electroluminescent device according to claim 17, ~~wherein~~ the barrier layer ~~has having~~ a sublayer in contact with the second electrode, the sublayer being composed of silicon nitride.

20. (Currently Amended) The method for manufacturing an electroluminescent device according to claim 17, ~~wherein the barrier layer has~~ having a sublayer in contact with the second electrode, the sublayer being composed of silicon nitride oxide.

21. (Currently Amended) The method for manufacturing an electroluminescent device according to claim 13, ~~wherein the barrier layer extends~~ extending to an insulating layer disposed around the second electrode, the insulating layer being composed of a silicon compound.